

HD74ALVC2G00

Dual 2-input NAND Gates

HITACHI

ADE-205-610B (Z)

Rev. 2
August 2001

Description

The HD74ALVC2G00 has two-input NAND gate in a 8 pin package. Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

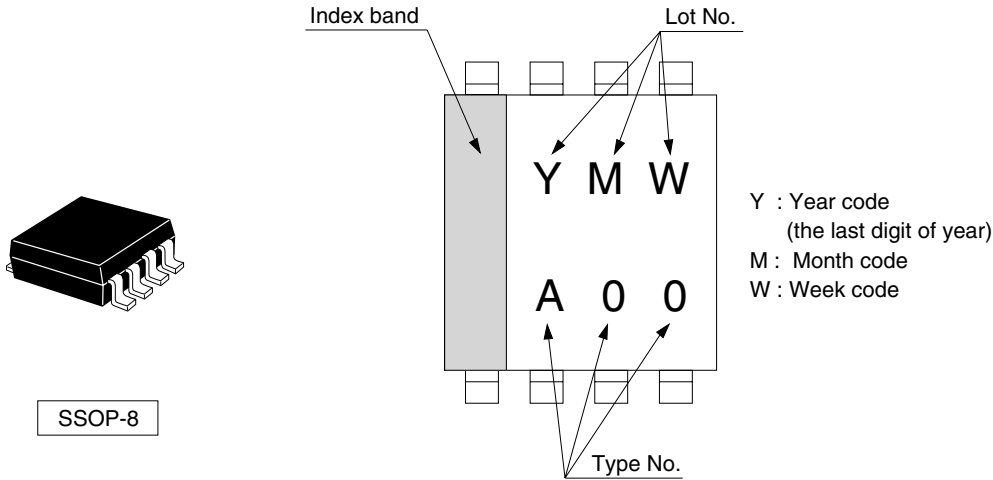
Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- Supply voltage range : 1.2 to 3.6 V
Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 3.6 V (@ V_{CC} = 0 V to 3.6 V)
All outputs V_O (Max.) = 3.6 V (@ V_{CC} = 0 V)
- Output current ± 2 mA (@ V_{CC} = 1.2 V)
 ± 4 mA (@ V_{CC} = 1.4 V to 1.6 V)
 ± 6 mA (@ V_{CC} = 1.65 V to 1.95 V)
 ± 18 mA (@ V_{CC} = 2.3 V to 2.7 V)
 ± 24 mA (@ V_{CC} = 3.0 V to 3.6 V)
- Package type

Package type	Package code	Package suffix	Taping code
SSOP-8 pin	TTP-8DB	US	E (3,000 pcs / Reel)

Outline and Article Indication

- HD74ALVC2G00

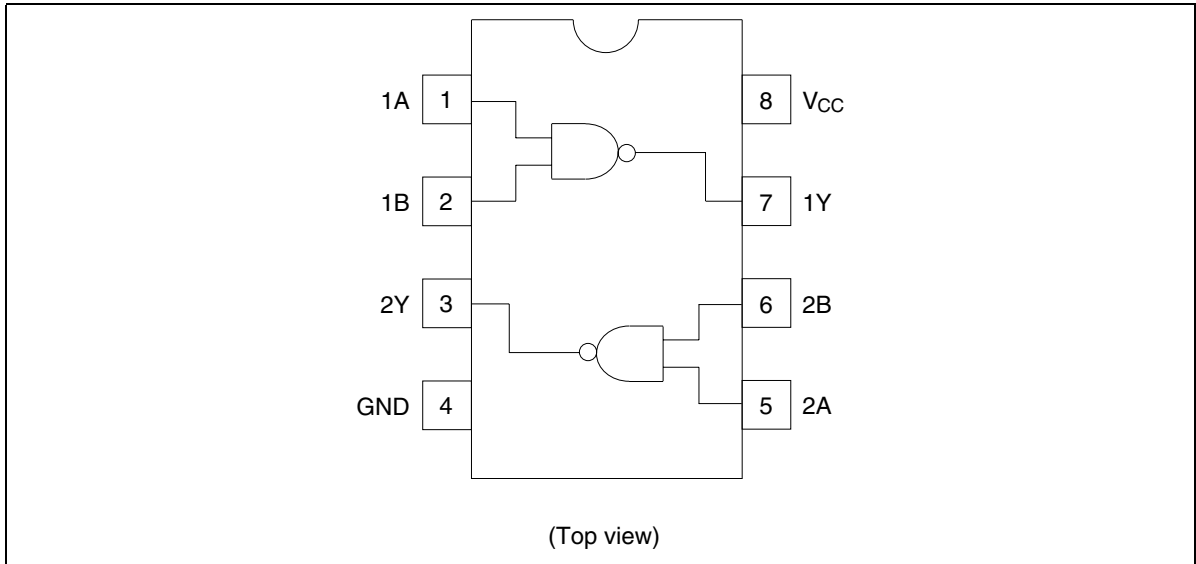


Function Table

Inputs		Output Y
A	B	
L	L	H
L	H	H
H	L	H
H	H	L

H: High level
L: Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V_{CC}	-0.5 to 4.6	V	
Input voltage range ^{*1}	V_I	-0.5 to 4.6	V	
Output voltage range ^{*1,2}	V_O	-0.5 to $V_{CC}+0.5$ -0.5 to 4.6	V	Output : H or L V_{CC} : OFF
Input clamp current	I_{IK}	-50	mA	$V_I < 0$
Output clamp current	I_{OK}	± 50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I_O	± 50	mA	$V_O = 0$ to V_{CC}
Continuous current through V_{CC} or GND	I_{CC} or I_{GND}	± 100	mA	
Maximum power dissipation at $T_a = 25^{\circ}\text{C}$ (in still air) ^{*3}	P_T	200	mW	
Storage temperature	T_{stg}	-65 to 150	$^{\circ}\text{C}$	

- Notes:
- The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.
 - 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 2. This value is limited to 4.6 V maximum.
 - 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	1.2	3.6	V	
Input voltage range	V _I	0	3.6	V	
Output voltage range	V _O	0	V _{CC}	V	
Output current	I _{OH}	—	−2	mA	V _{CC} = 1.2 V
		—	−4		V _{CC} = 1.4 V
		—	−6		V _{CC} = 1.65 V
		—	−18		V _{CC} = 2.3 V
		—	−24		V _{CC} = 3.0 V
		—	2		V _{CC} = 1.2 V
	I _{OL}	—	4		V _{CC} = 1.4 V
		—	6		V _{CC} = 1.65 V
		—	18		V _{CC} = 2.3 V
		—	24		V _{CC} = 3.0 V
Input transition rise or fall rate	$\Delta t / \Delta v$	0	20	ns / V	V _{CC} = 1.2 to 2.7 V
		0	10		V _{CC} = 3.3±0.3 V
Operating free-air temperature	Ta	−40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

(Ta = -40 to 85°C)

Item	Symbol	V _{cc} (V) †	Min	Typ	Max	Unit	Test conditions
Input voltage	V _{IH}	1.2	V _{cc} ×0.75	—	—	V	
		1.4 to 1.6	V _{cc} ×0.7	—	—		
		1.65 to 1.95	V _{cc} ×0.7	—	—		
		2.3 to 2.7	1.7	—	—		
		3.0 to 3.6	2.0	—	—		
	V _{IL}	1.2	—	—	V _{cc} ×0.25		
		1.4 to 1.6	—	—	V _{cc} ×0.3		
		1.65 to 1.95	—	—	V _{cc} ×0.3		
		2.3 to 2.7	—	—	0.7		
		3.0 to 3.6	—	—	0.8		
Output voltage	V _{OH}	Min to Max	V _{cc} -0.2	—	—	V	I _{OH} = -100 µA
		1.2	0.9	—	—		I _{OH} = -2 mA
		1.4	1.1	—	—		I _{OH} = -4 mA
		1.65	1.2	—	—		I _{OH} = -6 mA
		2.3	1.7	—	—		I _{OH} = -18 mA
		3.0	2.2	—	—		I _{OH} = -24 mA
	V _{OL}	Min to Max	—	—	0.2		I _{OL} = 100 µA
		1.2	—	—	0.3		I _{OL} = 2 mA
		1.4	—	—	0.3		I _{OL} = 4 mA
		1.65	—	—	0.3		I _{OL} = 6 mA
		2.3	—	—	0.55		I _{OL} = 18 mA
		3.0	—	—	0.55		I _{OL} = 24 mA
Input current	I _{IN}	3.6	—	—	±5	µA	V _{IN} = 3.6 V or GND
Quiescent supply current	I _{CC}	3.6	—	—	10	µA	V _{IN} = V _{CC} or GND, I _O = 0
Output leakage current	I _{OFF}	0	—	—	5	µA	V _{IN} or V _O = 0 to 3.6 V
Input capacitance	C _{IN}	3.3	—	4.5	—	pF	V _{IN} = V _{CC} or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

(Ta = -40 to 85°C)

- V_{CC} = 1.2 V

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time	t _{PLH} t _{PHL}	—	7.5	—	ns	C _L = 15 pF	A or B	Y

- V_{CC} = 1.5±0.1 V

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time	t _{PLH} t _{PHL}	2.0	—	7.0	ns	C _L = 15 pF	A or B	Y

- V_{CC} = 1.8±0.15 V

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time	t _{PLH} t _{PHL}	1.5	—	5.0	ns	C _L = 30 pF	A or B	Y

- V_{CC} = 2.5±0.2 V

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time	t _{PLH} t _{PHL}	1.0	—	3.7	ns	C _L = 30 pF	A or B	Y

- V_{CC} = 3.3±0.3 V

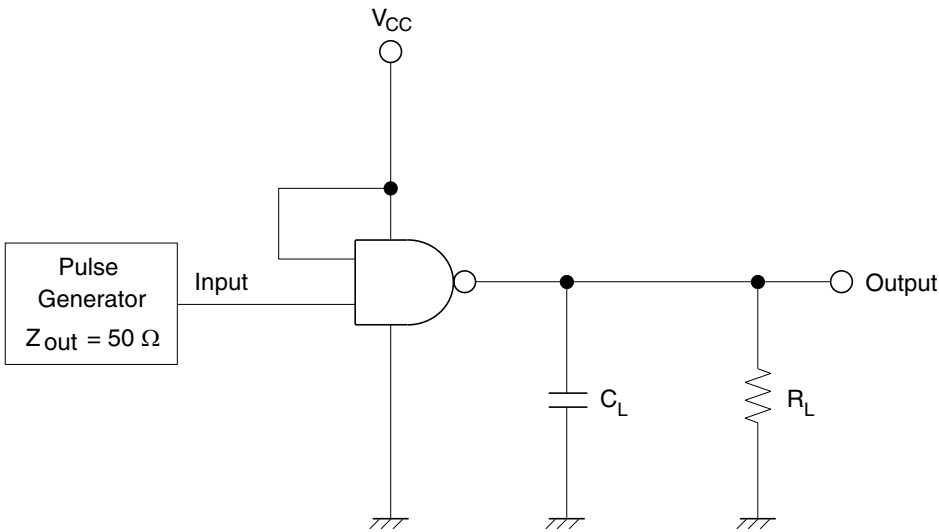
Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time	t _{PLH} t _{PHL}	1.0	—	2.8	ns	C _L = 30 pF	A or B	Y

Operating Characteristics

(Ta = 25°C)

Item	Symbol	V _{cc} (V)	Min	Typ	Max	Unit	Test conditions
Power dissipation capacitance	C _{PD}	1.5	—	10.5	—	pF	f = 10 MHz
		1.8	—	10.5	—		
		2.5	—	10.5	—		
		3.3	—	11.5	—		

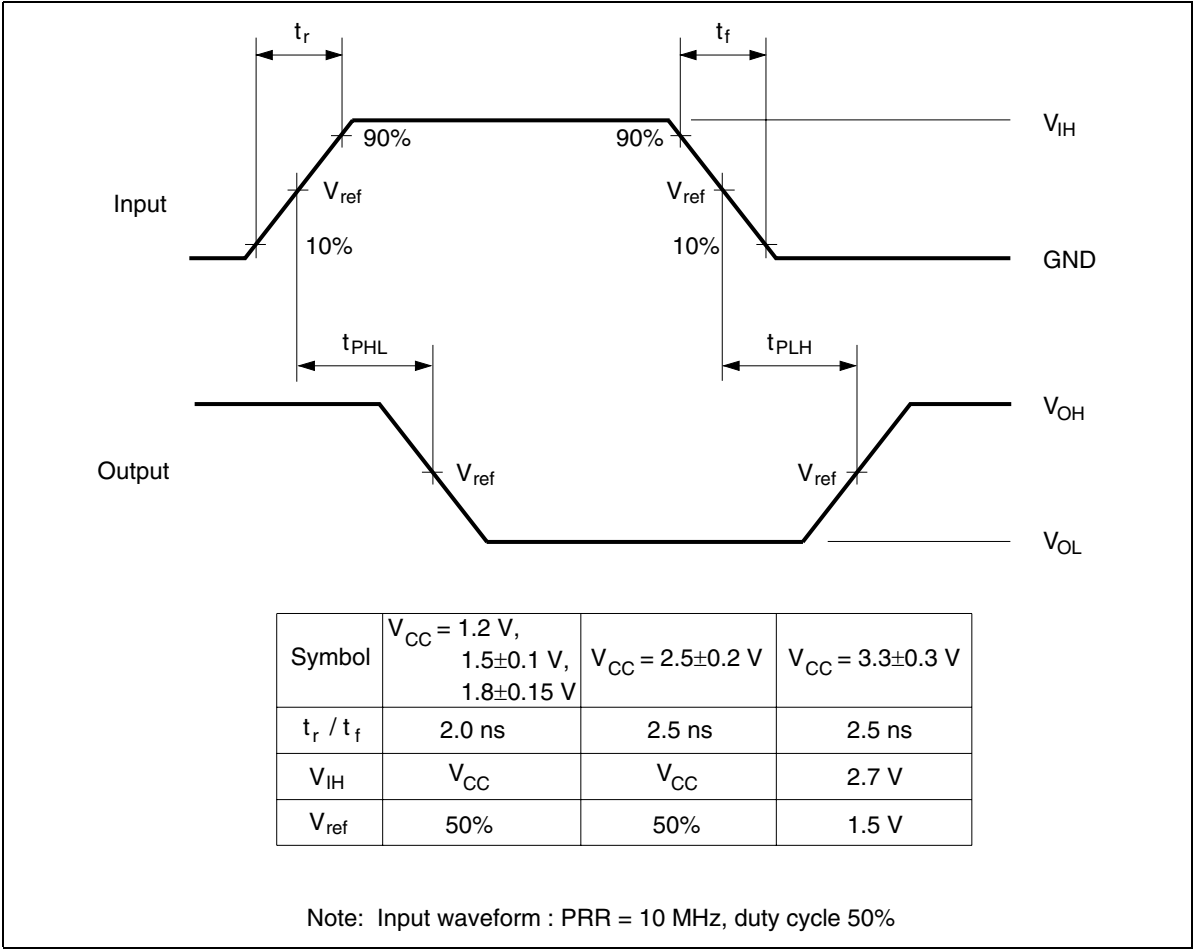
Test Circuit



Symbol	V _{CC} = 1.2 V, 1.5±0.1 V	V _{CC} = 1.8±0.15 V	V _{CC} = 2.5±0.2 V, 3.3±0.3 V
R _L	2.0 kΩ	1.0 kΩ	500 Ω
C _L	15 pF	30 pF	30 pF

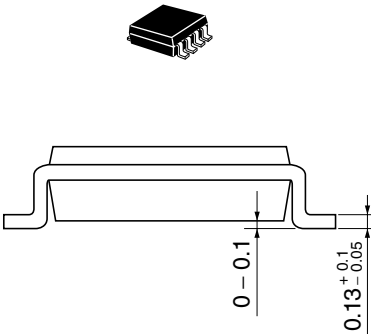
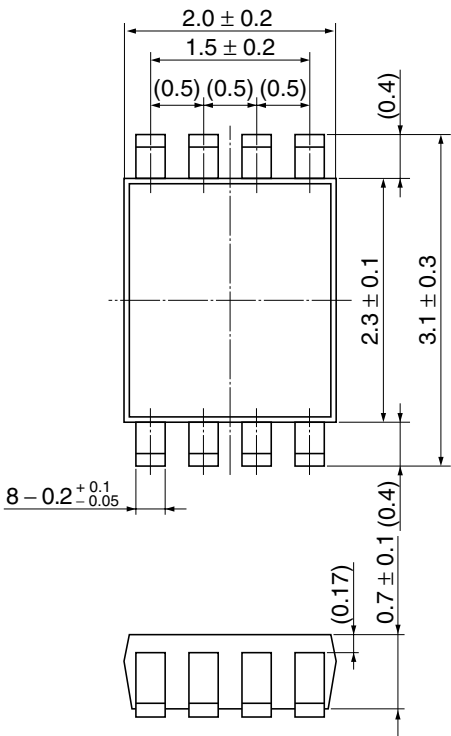
Note: C_L includes probe and jig capacitance.

Waveforms



Package Dimensions

As of July, 2001
Unit: mm



Hitachi Code	TTP-8DB
JEDEC	—
JEITA	—
Mass (reference value)	0.010 g

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